

L Number	Hits	Search Text	DB	Time stamp
1	2	("5286671").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 08:09
2	1		USPAT	2002/09/30 08:05
3	1		USPAT	2002/09/30 08:06
4	1		USPAT	2002/09/30 08:06
5	1		USPAT	2002/09/30 08:07
6	1		USPAT	2002/09/30 08:09
9	0	kurtz-anthony.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 08:13
10	124	kurtz-anthony-d.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 08:29
11	33	kurtz-anthony-d.in. and 'axis'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 08:30
16	1	("3654579").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 10:29
17	9	((('diode' and 'crystallographic') and 'p-n junction') and '100' and '111' and 'porous')	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:15
18	0	'p-n junction' and 'p-region' with 'porous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:16
19	2	'p-region' with 'porous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:19
20	0	'n-region' with 'non-porous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:19
21	17	'n-type' with 'non-porous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:29
22	15	'n-type' with 'non-porous' and 'p' with 'porous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:29
27	731	((257/104-106) or (257/46) or (259/109) or (438/380) or (438/983)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 14:16
28	68	((257/104-106) or (257/46) or (259/109) or (438/380) or (438/983)).CCLS.) and pressure	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 14:16

-	188	'p-n' with 'zener diode'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 08:04
-	7	('p-n' with 'zener diode') and crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:11
-	4	'p-n diode' and 'axis orientation'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:16
-	529	(257/627-628).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:17
-	159	((257/627-628).CCLS.) and diode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:21
-	118	((257/627-628).CCLS.) and diode and orientation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:09
-	64	((257/627-628).CCLS.) and 'p-n junction' and orientation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:49
-	20	((257/627-628).CCLS.) and 'p-' with '111' and 'n-' with '100'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:50
-	458297	'diode'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 16:59
-	3	'diode' and 'p-type' adj '111' and 'n-type' adj '100'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 17:21
-	1850	'diode' and 'crystallographic'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 17:24
-	311	('diode' and 'crystallographic') and 'p-n junction'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/26 17:24
-	138	(('diode' and 'crystallographic') and 'p-n junction') and '100' and '111'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/30 11:10